



AH3563Q

Description

The AH3563Q is an AEC-Q100 qualified high-voltage, high-sensitivity Hall effect omnipolar switch IC designed for position and proximity sensing in automotive applications, such as in seat and seatbelt buckle, steering lock/immobilization, gear stick, transmission actuator and gear position, HVAC compression, wiper, door/trunk closure, and so on. To support a wide range of demanding applications, the design is optimized to operate over the supply range of 3.0V to 28V. With chopper-stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3563Q provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a zener clamp on the supply. The output has an overcurrent limit and a zener clamp.

The single open-drain output can be switched on with south or north pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (B_{OP}), the output is switched on (pulled low) and is held on until the magnetic flux density B is lower than the release point (B_{RP}).

Features

- Omnipolar Operation
- High Sensitivity: BOP and BRP of ±30G and ±20G Typical
- Single Open-Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- Chopper Stabilized Design Provides
 - Superior Temperature Stability
 - Minimal Switch Point Drift
 - Enhanced Immunity to Stress
- Good RF Noise Immunity
- Reverse Blocking Diode
- Zener Clamp on Supply and Output Pins
- -40°C to +150°C Operating Temperature
- ESD: HBM > 8kV, CDM > 2kV
- Industry Standard SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The AH3563Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

HIGH VOLTAGE HIGH SENSITIVITY AUTOMOTIVE HALL EFFECT OMNIPOLAR SWITCH

Pin Assignments



Applications

- · Position and Proximity Sensing in Automotive Applications
- · Open and Close Detect
- Position Detect
- Level Detect
- Flow Meters
- Contactless Switches
- Seatbelt Buckle
- Seat Position

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit



Note: 4. C_{IN} is for power stabilization and to strengthen the noise immunity; the recommended capacitance is 10nF ~ 100nF.

Pin Descriptions

Packages: SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)							
Pin Number	Pin Name	Function					
1	Vdd	Power Supply Input					
2	GND	Ground					
3	OUTPUT	Output Pin					

Functional Block Diagram





Absolute Maximum Ratings (Notes 5 and 6) (@TA = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit	
Vdd	Supply Voltage (Note 6)		32	V	
Vddr	Reverse Supply Voltage (Note 6)	-32	V		
Vout_max	Output Off Voltage (Note 6)	t Off Voltage (Note 6)			
Іоит	Continuous Output Current	60	mA		
IOUT_R	Reverse Output Current	-50 mA			
В	Magnetic Flux Density		Unlimited	•	
PD	Package Power Dissipation	SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)	550	mW	
		SOT23	230	1	
Ts	Storage Temperature Range		-65 to +165	°C	
TJ	Maximum Junction Temperature		+150	°C	
ESD HBM	Electros Static Discharge Withstand — Human Body Model	(HBM)	8	kV	
ESD MM	Electros Static Discharge Withstand — Machine Model (MM	1)	800	V	
ESD CDM	Electros Static Discharge Withstand — Charged Device Mo	del (CDM)	2	kV	

Notes: 5. Stresses greater than the 'Absolute Maximum Ratings' specified above can cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

6. The absolute maximum V_{DD} of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

Recommended Operating Conditions (@TA = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Condition	Rating	Unit
Vdd	Supply Voltage	Operating	3.0 to 28	V
TA	Operating Temperature Range	Operating	-40 to +150	°C

Electrical Characteristics (Notes 7 and 8) (@T_A = -40°C to +150°C, V_{DD} = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Condition	Min	Тур	Max	Unit
Vout_on	Output On Voltage	IOUT = 20mA, B > BOP	_	0.2	0.4	V
I _{LKG}	Output Leakage Current (When Output is Off)	Vout = 28V, B < B _{RP} , Output Off	—	0.1	10	μA
laa	Supply Current	Output Open, T _A = +25°C	—	3	3.5	mA
IDD	Supply Culterit	Output Open, T _A = -40°C to +150°C	—	_	4	mA
		V _{DD} = -18V, T _A = +25°C	—	0.6	—	μA
	Deverse Supply Current	V _{DD} = -18V, T _A = -40°C to +150°C	—	0.6	1500	μA
IDD_R	Reverse Supply Current	V _{DD} = -28V, T _A = +25°C	—	1.6	—	μA
		V _{DD} = -28V, T _A = -40°C to +150°C	—	1.6	2500	μA
tp_on	Device Power-On Time (Start-up Time)	$V_{DD} \ge 3V, B \ge B_{OP}$ (Note 7)	—	10	—	μs
fc	Chopping Frequency	—	—	800	—	kHz
t _D	Response Time Delay (Time from Magnetic Threshold Reached to the Start of the Output Rise or Fall)	(Note 9)	_	3.75	_	μs
tR	Output Rising Time (External Pull-up Resistor RL and Load Capacitance Dependent)	$R_L = 1k\Omega, C_L = 20pF$	_	0.2	1	μs
Output Falling Time tF (Internal Switch Resistance and Load Capacitance Dependent)		$R_L = 1k\Omega$, $C_L = 20pF$	_	0.1	1	μs
IOCL	Output Current Limit	B > B _{OP} (Note 10)	30	_	55	mA
Vz	Zener Clamp Voltage	I _{DD} = 5mA	28	_		V

Notes: 7. When power is initially turned on, V_{DD} must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.

8. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control, and characterization.

9. Guaranteed by design, process control, and characterization. Not tested in production.

10. The device will limit the output current I_{OUT} to current limit of I_{OC}.



Magnetic Characteristics (Notes 11 and 12) (TA = -40°C to +150°C, VDD = 3.0V to 28V, unless otherwise specified.)

					(1mT =	10 Gauss)
Symbol	Parameter	Condition	Min	Тур	Max	Unit
B _{OPS} (South Pole to the Part Marking Side)		$V_{DD} = 12V, T_A = +25^{\circ}C$	—	30		
BOPS (South Pole to the Part Marking Side)	Operation Point	T _A = -40°C to +150°C	15	30	45	
Denv (North Dolo to the Dort Marking Side)		$V_{DD} = 12V, T_A = +25^{\circ}C$	—	-30	_	
PN (North Pole to the Part Marking Side)		$T_{A} = -40^{\circ}C \text{ to } +150^{\circ}C$	-45	-30	-15	
Para (South Polo to the Port Marking Side)		$V_{DD} = 12V, T_A = +25^{\circ}C$	—	20	-	Gauss
BRPS (South Pole to the Part Marking Side)	Release Point	$T_{A} = -40^{\circ}C \text{ to } +150^{\circ}C$	5	20	35	Causs
Provide Courth Date to the Dart Marking Cide)	Release Folli	$V_{DD} = 12V, T_A = +25^{\circ}C$	—	-20	-	
B _{RPN} (South Pole to the Part Marking Side)		T _A = -40°C to +150°C	-35	-20	-5	
	Hysteresis (Note 13)	$V_{DD} = 12V, T_A = +25^{\circ}C$	—	10	-	
Bhy (Bopx - Brpx)	Hysielesis (Note 13)	T _A = -40°C to +150°C	5	10	18	

11. When power is initially turned on, VDD must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid Notes: after the start-up time of 10µs typical from the operating voltage reaching 3V.

12. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization. 13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.







Typical Operating Characteristics

Output Switch Operate and Release Points (Magnetic Thresholds) - BOPS and BRPS



Switch Points BOPS and BRPS vs Supply Voltage



Temperature (°C)

Switch Points B_{OPS} and B_{RPS} vs Temperature







Switch Points B_{OPS} and B_{RPS} vs Temperature



Switch Points B_{OPS} and B_{RPS} vs Temperature



Supply Current vs Temperature



Typical Operating Characteristics (Continued)

Supply Reverse Current



Supply Voltage (V) Reverse Supply Current vs Supply Voltage



Reverse Supply Current vs Temperature



Output ON Voltage vs Supply Voltage







Output Leakage Current vs Temperature

Output Sv	witch L	eakage	Current
-			



Output Leakage Current vs Supply Voltage



AH3563Q

Typical Operating Characteristics (Continued)

Output Current Limit





Thermal Performance Characteristics

(1) Package Type: SOT23

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



(2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0



Power Dissipation Curve





Ordering Information



			B	Bulk	Ammo	Box	7" Tape and Reel		
Part Number	Package Code	Packaging	Quantity	Part Number Suffix	Quantity	Part Number Suffix	Quantity	Part Number Suffix	
AH3563Q-P-A	Р	SIP-3 (Ammo Pack)	NA	NA	4,000/Box	-A	NA	NA	
AH3563Q-P-B	Р	SIP-3 (Bulk Pack)	1000	-B	NA	NA	NA	NA	
AH3563Q-SA-7	SA	SOT23	NA	NA	NA	NA	3,000/Tape & Reel	-7	

Notes: 14. Ammo Box is for SIP-3 (Ammo Pack) Spread Lead. 15. Bulk is for SIP-3 (Bulk Pack) Straight Lead.

Marking Information

(1) Package Type: SOT23



Part Number	Package	Identification Code
AH3563Q-SA-7	SOT23	Z3

(2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)



Part Number	Package	Identification Code		
AH3563Q-P-A	SIP-3 (Ammo Pack)	3563Q		
AH3563Q-P-B	SIP-3 (Bulk Pack)	3563Q		



Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT23



	SO	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
Н	2.80	3.00	2.90
J	0.013	0.10	0.05
К	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
М	0.085	0.150	0.110
а	0°	8°	_
All	Dimens	ions in	mm

Min/Max



Sensor Location



Package Outline Dimensions (Continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(2) Package Type: SIP-3 (Bulk Pack)



SIP-3 (Bulk Pack)				
Dim	Min	Max	Тур	
Α	1.40	1.60	1.50	
b	0.33	0.43	0.38	
b2	0.40	0.508	0.46	
С	0.35	0.41	0.38	
D	3.90	4.30	4.10	
E	2.80	3.20	3.00	
e1	1.24	1.30	1.27	
F	0.00	0.20		
J	2.62 REF			
L	14.00	15.00	14.50	
L1	1.55	1.75	1.65	
s	0.63	0.84	0.74	
a1			5°	
a2			5°	
a3			45°	
a4			3°	
All Dimensions in mm				

Min/Max



Sensor Location



Package Outline Dimensions (Continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(3) Package Type: SIP-3 (Ammo Pack)



1	SIE	1.2		
SIP-3 (Ammo Pack)				
Dim	Min	Max	Тур	
Α	1.40	1.60	1.50	
b	0.33	0.43	0.38	
b2a	0.40	0.52	0.46	
C	0.35	0.41	0.38	
D	3.90	4.30	4.10	
E	2.80	3.20	3.00	
e1	1.24	1.30	1.27	
e2	2.40	2.90	2.65	
F	0.00	0.20	—	
J	2.62 REF			
L	14.00	15.00	14.50	
La	12.90	14.90	13.90	
L1	1.55	1.75	1.65	
L3	2.00	3.00	2.50	
S	0.63	0.84	0.74	
a1	_	_	5°	
a2	_		5°	
a3	_		45°	
a4	_		3°	
All Dimensions in mm				

Min/Max



Sensor Location



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

Mechanical Data

SOT23 Package

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.009 grams (Approximate)

SIP-3 (Bulk Pack), SIP-3 (Ammo Pack) Packages

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.12 grams (Approximate)



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